

MOSFET - Power, Single N-Channel, TOLL 60 V, 0.9 mΩ, 422 A

NVBLS001N06C

Features

- Low $R_{DS(on)}$ to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- Lowers Switching Noise/EMI
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	60	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain Current R _{θJC} (Note 2)	Steady State	T _C = 25°C	I _D	422	A
		T _C = 100°C		298	
Power Dissipation R _{θJC} (Note 2)		T _C = 25°C	P _D	284	W
		T _C = 100°C		142	
Continuous Drain Current R _{θJA} (Notes 1, 2)	Steady State	T _A = 25°C	I _D	51	A
		T _A = 100°C		36	
Power Dissipation R _{θJA} (Notes 1, 2)		T _A = 25°C	P _D	4.2	W
		T _A = 100°C		2.1	
Pulsed Drain Current	T _A = 25°C, t _p = 10 μs		I _{DM}	900	A
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			I _S	236	A
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 39 A)			E _{AS}	1640	mJ
Lead Temperature Soldering Reflow for Soldering Purposes (1/8" from case for 10 s)			T _L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case – Steady State (Note 2)	$R_{\theta JC}$	0.53	$^\circ\text{C/W}$
Junction-to-Ambient – Steady State (Note 2)	$R_{\theta JA}$	36	

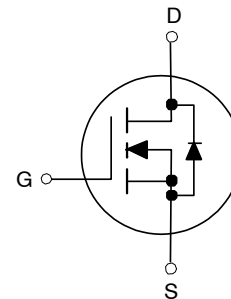
1. Surface-mounted on FR4 board using a 1 in² pad size, 2 oz. Cu pad.
2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.



ON Semiconductor®

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$V_{(BR)DSS}$	$R_{DS(ON)} \text{ MAX}$	$I_D \text{ MAX}$
60 V	0.9 mΩ @ 10 V	422 A



H-PSOF8L
CASE 100CU

ORDERING INFORMATION

Device	Package	Shipping†
NVBLS001N06C	H-PSOF8L (Pb-Free)	2000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NVBL5001N06C

Table 1. ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Units
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 250\ \mu\text{A}$, $V_{GS} = 0\ \text{V}$		60			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	$V_{(BR)DSS}/T_J$	$I_D = 562\ \mu\text{A}$, ref to 25°C			26		mV/ $^\circ\text{C}$
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 60\ \text{V}$, $V_{GS} = 0\ \text{V}$	$T_J = 25^\circ\text{C}$			10	μA
			$T_J = 125^\circ\text{C}$			100	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{DS} = 0\ \text{V}$, $V_{GS} = 20\ \text{V}$				100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS} = V_{DS}$, $I_D = 562\ \mu\text{A}$		2.0	2.8	4.0	V
Negative Threshold Temperature Coefficient	$V_{GS(th)}/T_J$	$I_D = 562\ \mu\text{A}$, ref to 25°C			9.9		mV/ $^\circ\text{C}$
Drain-to-Source On Resistance	$R_{DS(on)}$	$V_{GS} = 10\ \text{V}$, $I_D = 80\ \text{A}$			0.75	0.9	m Ω
Forward Transconductance	g_{FS}	$V_{DS} = 5\ \text{V}$, $I_D = 80\ \text{A}$			290		S
CHARGES & CAPACITANCES							
Input Capacitance	C_{iss}	$V_{GS} = 0\ \text{V}$, $V_{DS} = 30\ \text{V}$, $f = 10\ \text{kHz}$			11575		pF
Output Capacitance	C_{oss}				5973		pF
Reverse Transfer Capacitance	C_{rss}				76		pF
Total Gate Charge	$Q_{G(tot)}$	$V_{GS} = 10\ \text{V}$, $V_{DS} = 30\ \text{V}$, $I_D = 80\ \text{A}$			143		nC
Threshold Gate Charge	$Q_{G(th)}$				31		nC
Gate-to-Source Charge	Q_{gs}				54		nC
Gate-to-Drain Charge	Q_{gd}				13		nC
SWITCHING CHARACTERISTICS, $V_{GS} = 10\ \text{V}$ (Note 3)							
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = 10\ \text{V}$, $V_{DS} = 30\ \text{V}$, $I_D = 80\ \text{A}$, $R_G = 6\ \Omega$			34		ns
Rise Time	t_r				53		ns
Turn-Off Delay Time	$t_{d(off)}$				119		ns
Fall Time	t_f				91		ns
DRAIN-SOURCE DIODE CHARACTERISTICS							
Forward Diode Voltage	V_{SD}	$I_S = 80\ \text{A}$, $V_{GS} = 0\ \text{V}$	$T_J = 25^\circ\text{C}$		0.79	1.2	V
		$I_S = 80\ \text{A}$, $V_{GS} = 0\ \text{V}$	$T_J = 125^\circ\text{C}$		0.66		V
Reverse Recovery Time	t_{rr}	$V_{GS} = 0\ \text{V}$, $dI_S/dt = 100\ \text{A}/\mu\text{s}$, $I_S = 56\ \text{A}$			120		ns
Charge Time	t_a				60		ns
Discharge Time	t_b				60		ns
Reverse Recovery Charge	Q_{rr}				322		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

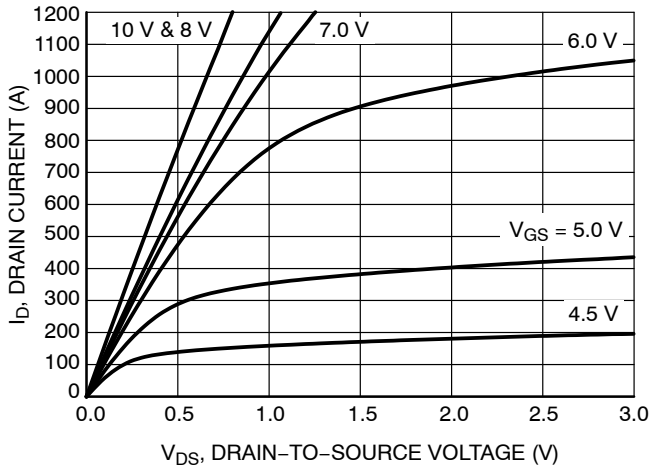


Figure 1. On-Region Characteristics

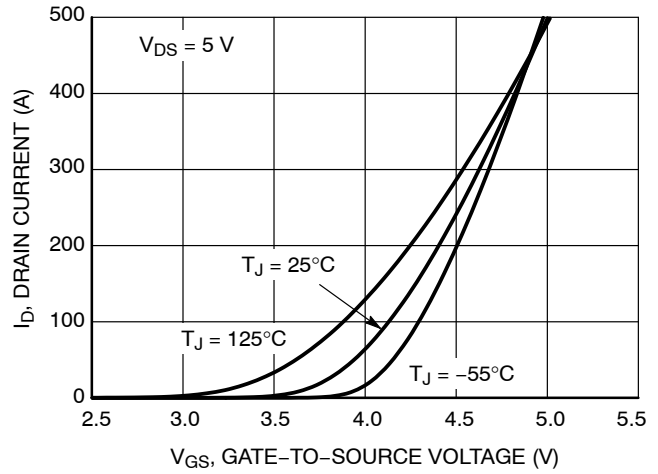


Figure 2. Transfer Characteristics

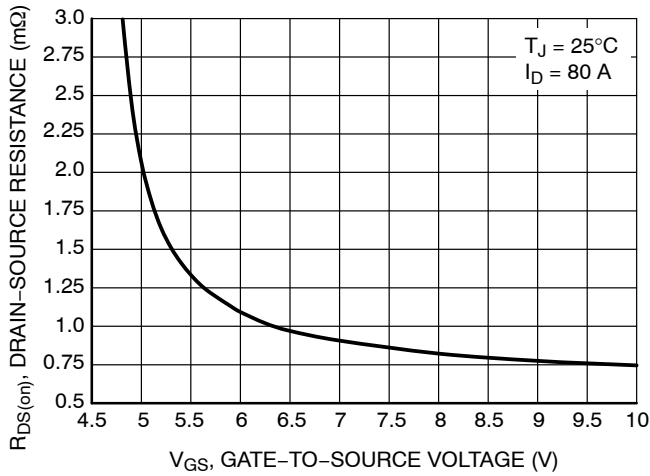


Figure 3. On-Resistance vs. V_{GS}

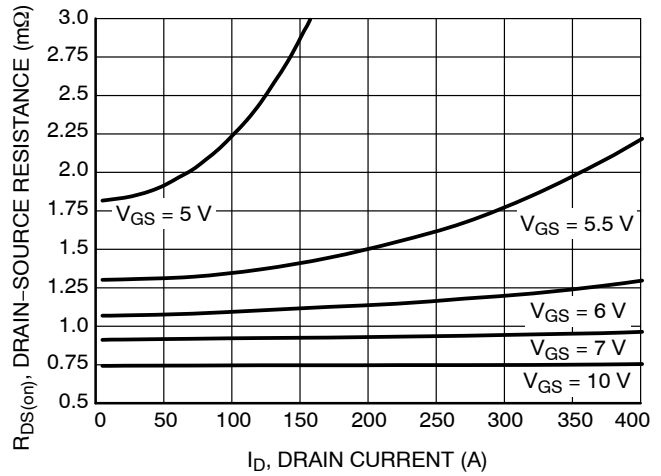


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

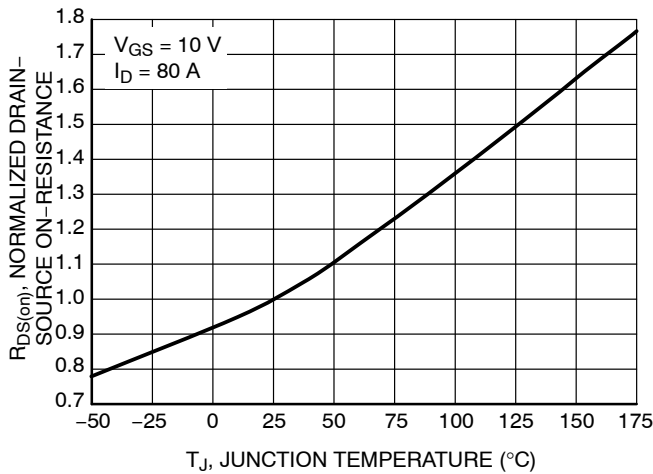


Figure 5. On-Resistance Variation with Temperature

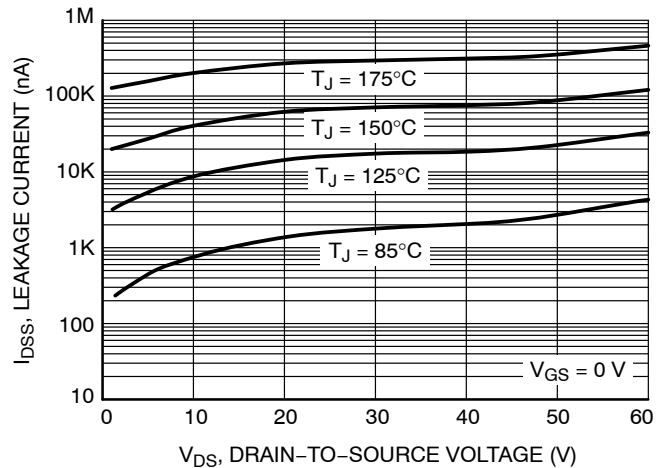


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS

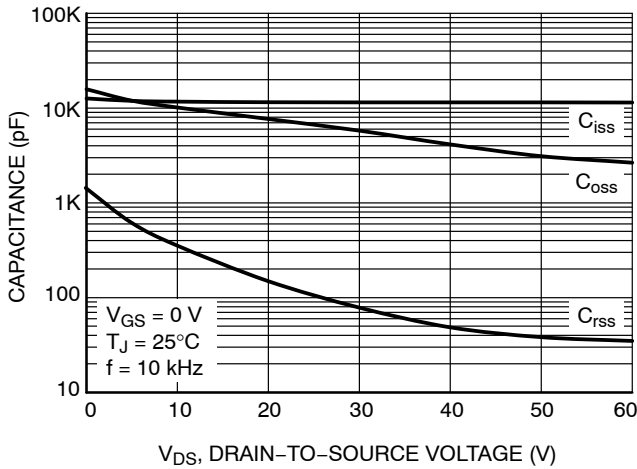


Figure 7. Capacitance Variation

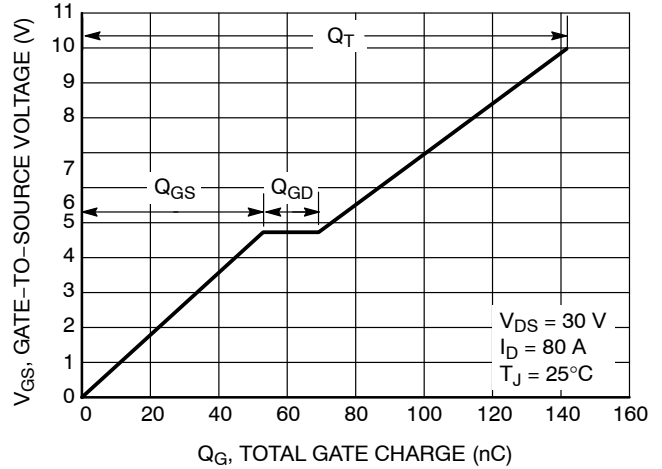


Figure 8. Gate-to-Source Voltage vs. Total Gate Charge

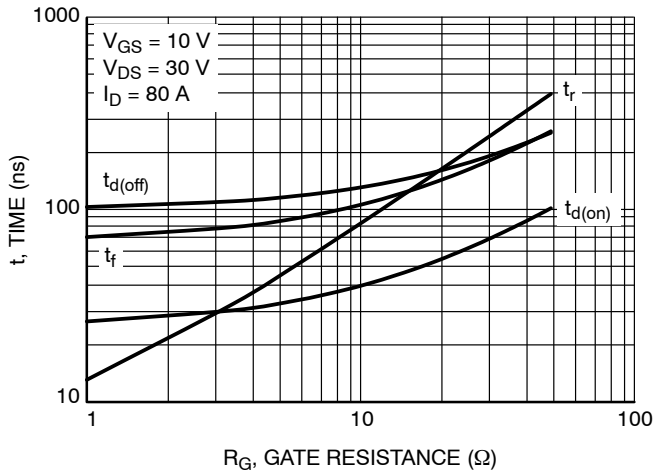


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

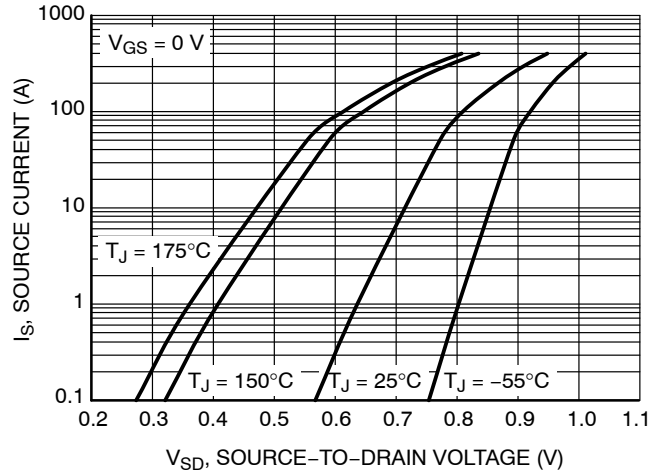


Figure 10. Diode Forward Voltage vs. Current

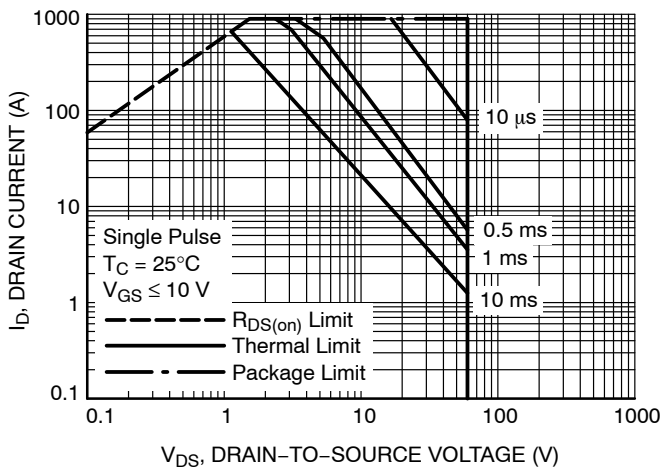


Figure 11. Maximum Rated Forward Biased Safe Operating Area

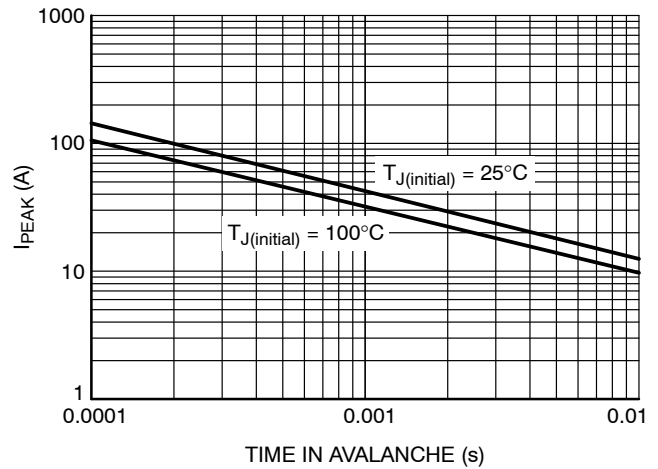


Figure 12. Avalanche Characteristics

TYPICAL CHARACTERISTICS

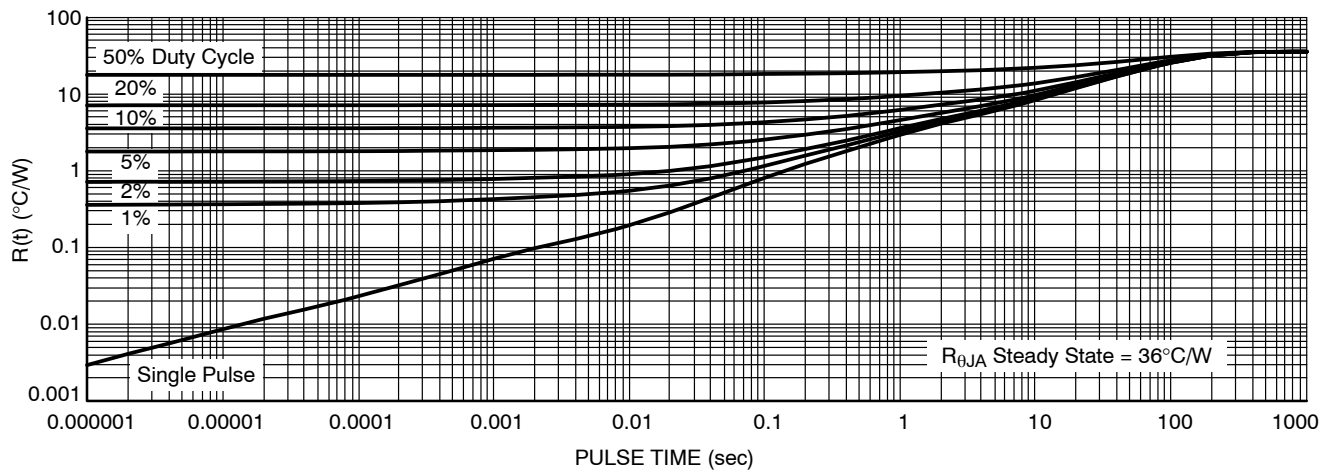


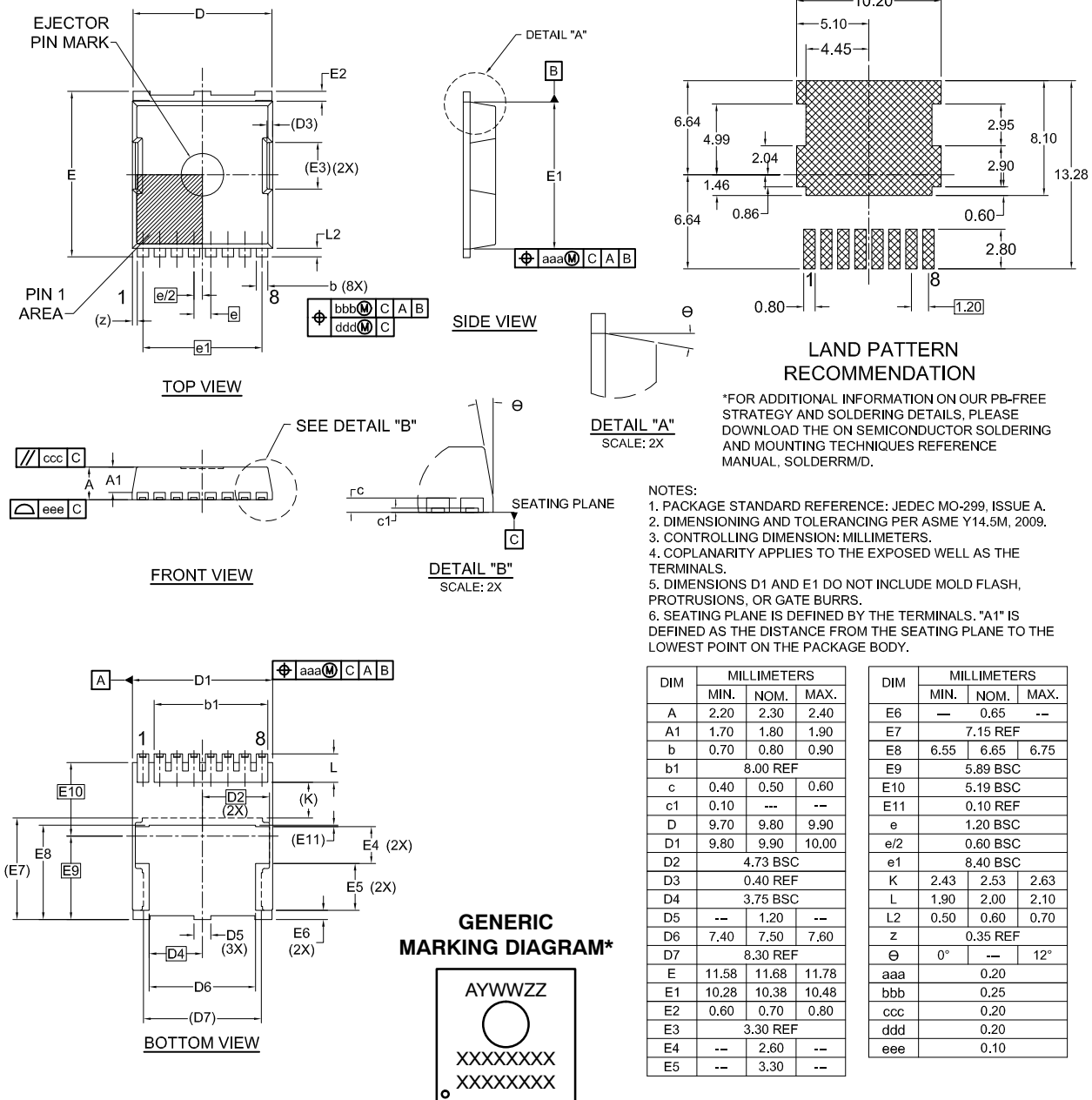
Figure 13. Thermal Characteristics (Junction-to-Ambient)

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



H-PSOF8L 11.68x9.80 CASE 100CU ISSUE B

DATE 20 MAY 2022



A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code
XXXX = Specific Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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